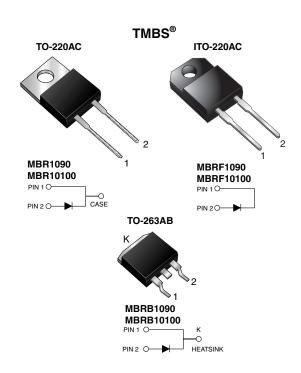
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New Product MBR(F,B)1090 & MBR(F,B)10100

Vishay General Semiconductor

## **High-Voltage Schottky Rectifier**



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	10 A				
V <sub>RRM</sub>	90 V, 100 V				
I <sub>FSM</sub>	150 A				
V <sub>F</sub>	0.65 V				
T <sub>J</sub> max.	150 °C				

### FEATURES

- Trench MOS Schottky technology
- Lower power losses, high efficiency
- Low forward voltage drop
- High forward surge capability
- High frequency operation
- Meets MSL level 1, per J-STD-020, LF maximum peak of 245 °C (for TO-263AB package)
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106 (for TO-220AC and ITO-220AC package)
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

#### **TYPICAL APPLICATIONS**

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, dc-to-dc converters or polarity protection application.

### **MECHANICAL DATA**

Case: TO-220AC, ITO-220AC, TO-263AB

Molding compound meets UL 94 V-0 flammability rating

Base P/N-E3 - RoHS compliant, commercial grade

**Terminals:** Matte tin plated leads, solderable per J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: As marked

Mounting Torque: 10 in-lbs maximum

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR1090	MBR10100	UNIT		
Maximum repetitive peak reverse voltage	V <sub>RRM</sub>	90 100		V		
Working peak reverse voltage	V <sub>RWM</sub>	90 100		V		
Maximum DC blocking voltage	V <sub>DC</sub>	90	100	V		
Maximum average forward rectified current at $T_C$ = 133 °C	I <sub>F(AV)</sub>	10		А		
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load	I <sub>FSM</sub>	150		A		
Non-repetitive avalanche energy at $T_J = 25$ °C, L = 60 mH	E <sub>AS</sub>	130		mJ		
Peak repetitive reverse current at $t_p = 2 \mu s$ , 1 kHz, T <sub>J</sub> = 38 °C ± 2 °C	I <sub>RRM</sub>	0.5		A		
Voltage rate of change (rated V <sub>R</sub> )	dV/dt	10 000		V/µs		
Isolation voltage (ITO-220AC only) From terminal to heatsink t = 1 min	V <sub>AC</sub>	1500		V		
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 150		°C		

Document Number: 89034 Revision: 24-Jun-09 For technical questions within your region, please contact one of the following: PDD-Americas@vishay.com, PDD-Asia@vishay.com, PDD-Europe@vishay.com



COMPLIANT

# MBR(F,B)1090 & MBR(F,B)10100

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<b>ELECTRICAL CHARACTERISTICS</b> ( $T_C = 25$ °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	VALUE	UNIT		
Maximum instantaneous forward voltage <sup>(1)</sup>	I <sub>F</sub> = 10 A I <sub>F</sub> = 10 A I <sub>F</sub> = 20 A	T <sub>C</sub> = 25 °C T <sub>C</sub> = 125 °C T <sub>C</sub> = 125 °C	V <sub>F</sub>	0.80 0.65 0.75	V		
Maximum reverse current at working peak reverse voltage <sup>(2)</sup>		T <sub>J</sub> = 25 °C T <sub>J</sub> = 100 °C	I <sub>R</sub>	100 6.0	μA mA		

#### Notes

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

<sup>(2)</sup> Pulse test: Pulse width  $\leq$  40 ms

<b>THERMAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)					
PARAMETER	SYMBOL	MBR	MBRF	MBRB	UNIT
Typical thermal resistance	$R_{ extsf{ heta}JA}$ $R_{ extsf{ heta}JC}$	60 2.0	- 3.5	60 2.0	°C/W

ORDERING INFORMATION (Example)							
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE		
TO-220AC	MBR10100-E3/4W	1.845	4W	50/tube	Tube		
ITO-220AC	MBRF10100-E3/4W	1.661	4W	50/tube	Tube		
TO-263AB	MBRB10100-E3/4W	1.384	4W	50/tube	Tube		
TO-263AB	MBRB10100-E3/8W	1.384	8W	800/reel	Tape and reel		

#### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

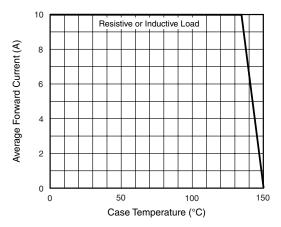


Figure 1. Forward Current Derating Curve

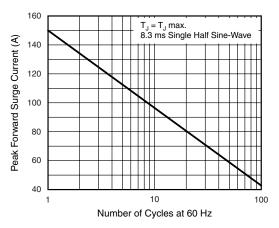


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current





MBR(F,B)1090 & MBR(F,B)10100

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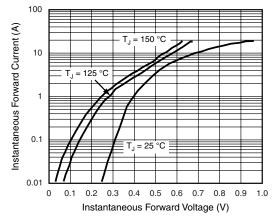


Figure 3. Typical Instantaneous Forward Characteristics

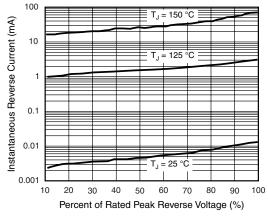


Figure 4. Typical Reverse Characteristics

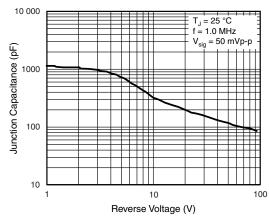


Figure 5. Typical Junction Capacitance

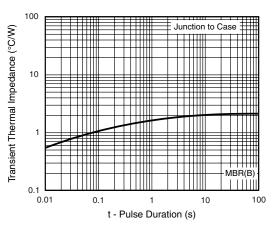


Figure 6. Typical Transient Thermal Impedance

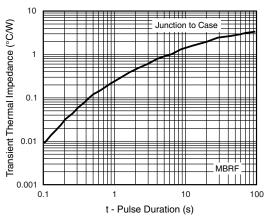
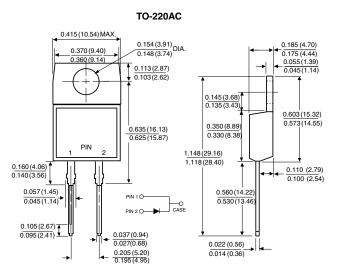


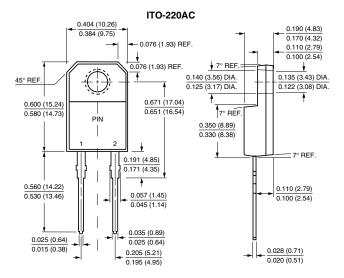
Figure 7. Typical Transient Thermal Impedance

# MBR(F,B)1090 & MBR(F,B)10100

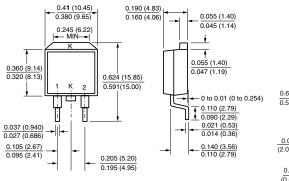
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### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

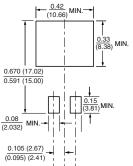




TO-263AB



#### Mounting Pad Layout







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